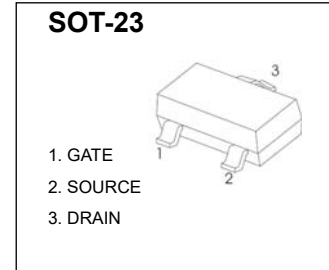




SOT-23 Plastic-Encapsulate MOSFETS

CJ2309A P-Channel Enhancement Mode Field Effect Transistor

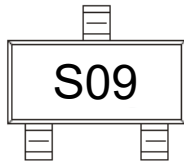
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-60V	190mΩ@-10V	-2A
	240mΩ@-4.5V	



DESCRIPTION

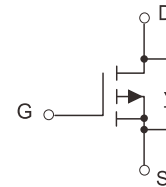
The CJ2309A uses advanced trench technology to provide excellent $R_{DS(on)}$. This device is suitable for use as a uni-directional or bi-directional load switch.

MARKING



S09 = Device code

Equivalent Circuit



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	±20	
Continuous Drain Current	I_D	-2	A
Pulsed Drain Current	I_{DM}	-8	
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}C/W$
Power Dissipation ($T_c=25^{\circ}C$)	P_D	2.5	W
Thermal Resistance from Junction to Case ($T_c=25^{\circ}C$)	$R_{\theta JC}$	50	$^{\circ}C/W$
Operation Junction and Storage Temperature Range	T_J, T_{stg}	-55 ~ +150	$^{\circ}C$

MOSFET ELECTRICAL CHARACTERISTICS

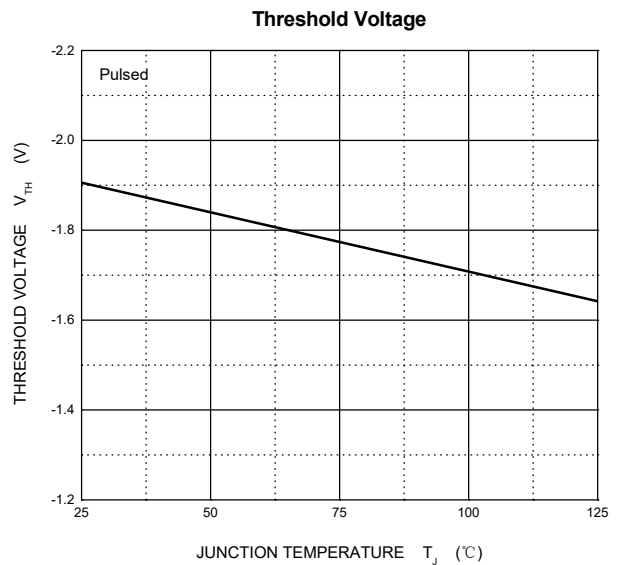
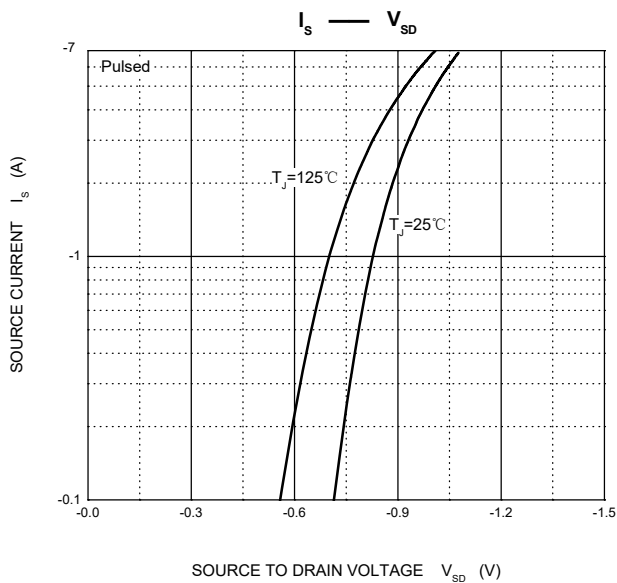
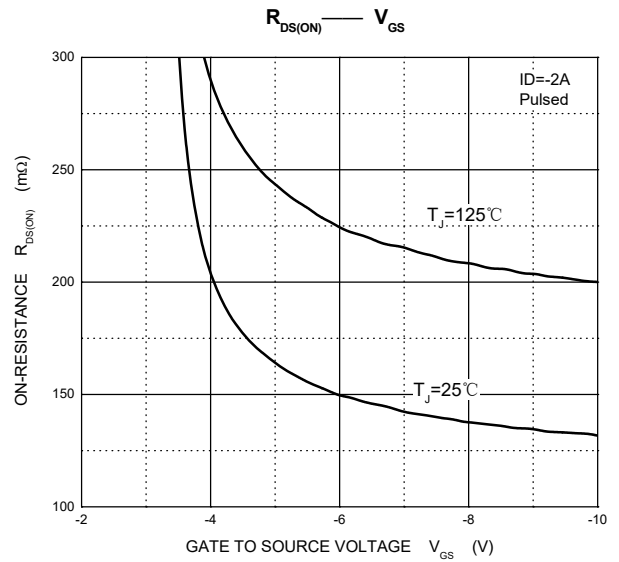
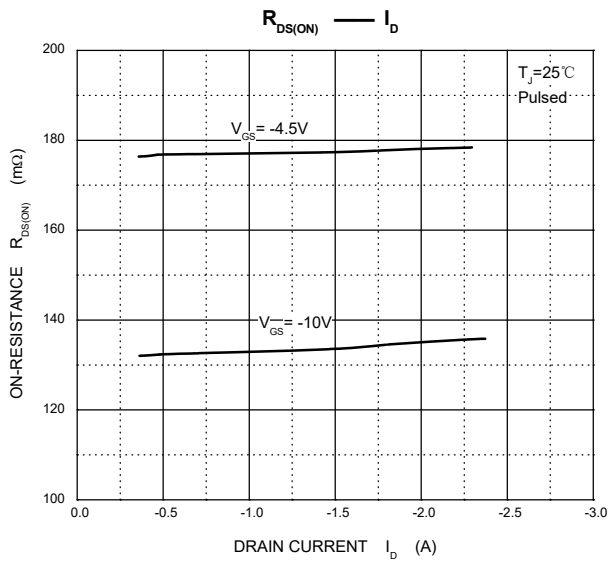
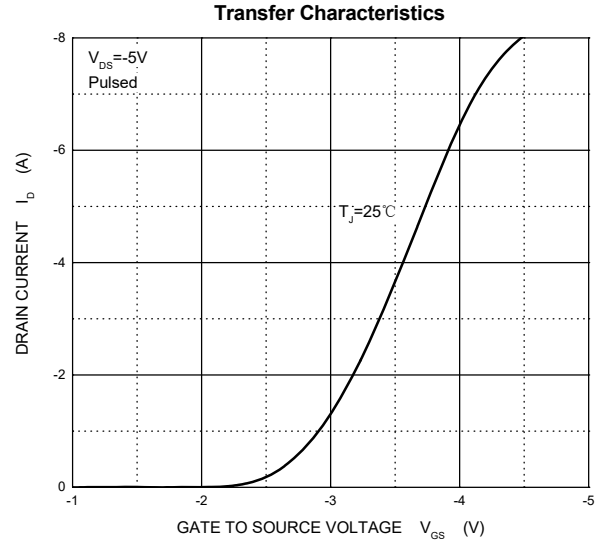
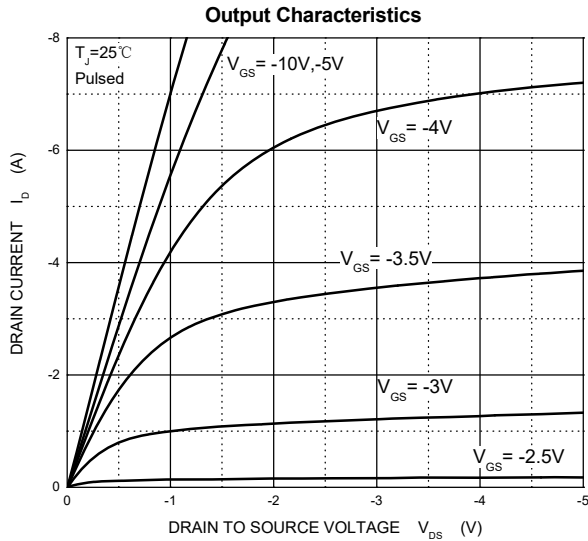
$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -60V, V_{GS} = 0V, T_J = 25\text{ }^\circ\text{C}$			-1	μA
		$V_{DS} = -60V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$			-1	mA
Gate-source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On characteristics						
Drain-source on-resistance ^②	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -2A$		130	190	m Ω
		$V_{GS} = -4.5V, I_D = -1.5A$		180	240	m Ω
Forward transconductance	g_{FS}	$V_{DS} = -10V, I_D = -2A$		3.1		S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.9	-2.5	V
Dynamic Characteristics^③						
Input capacitance	C_{iss}	$V_{DS} = -30V, V_{GS} = 0V, f = 1MHz$		380		pF
Output capacitance	C_{oss}			32		pF
Reverse transfer capacitance	C_{rss}			6		pF
Gate resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		17		Ω
Switching Characteristics^③						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = -10V, V_{DD} = -30V$ $, I_D = -1.5A, R_G = 3\Omega$		45		ns
Turn-on rise time	t_r			38		ns
Turn-off delay time	$t_{d(off)}$			18		ns
Turn-off fall time	t_f			15		ns
Total Gate Charge	Q_g	$V_{DS} = -30V, I_D = -1.5A, V_{GS} = -10V$		12		nC
Gate-Source Charge	Q_{gs}			2.5		nC
Gate-Drain Charge	Q_{gd}			3.9		nC
Drain-source diode characteristics and maximum ratings						
Diode forward voltage ^②	V_{SD}	$I_S = -1A, V_{GS} = 0V$		-0.81	-1	V
Continuous drain-source diode forward current	I_S				-1.6	A
Pulsed drain-source diode forward current ^①	I_{SM}				-8	A

Notes:

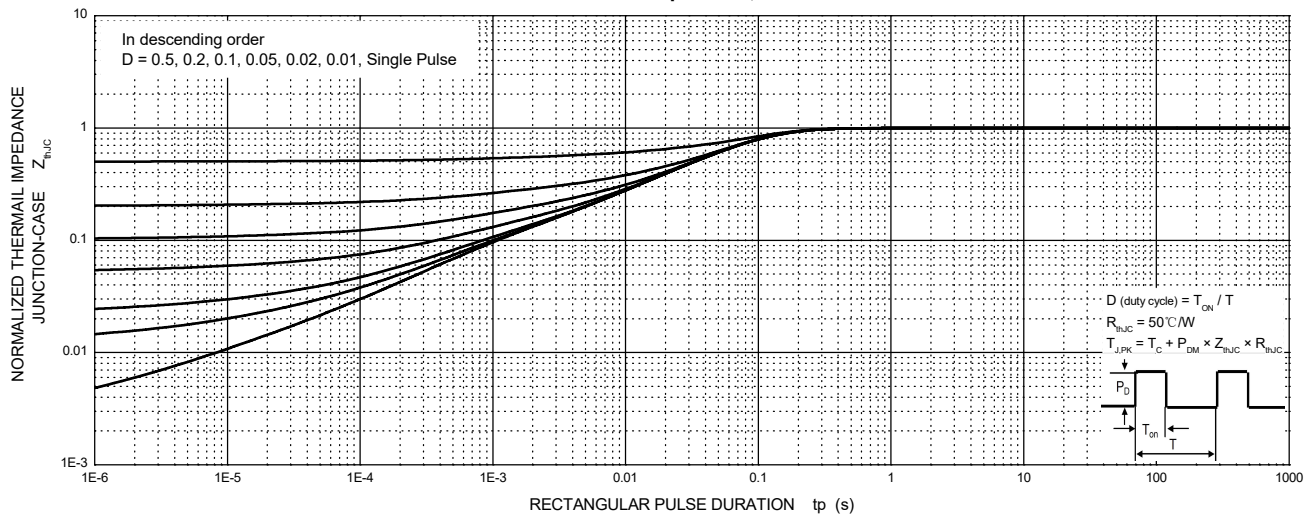
- 1.Repetitive Rating : Pulse width limited by maximum junction temperature.
- 2.Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- 3.Guaranteed by design, not subject to production testing.

Typical Characteristics

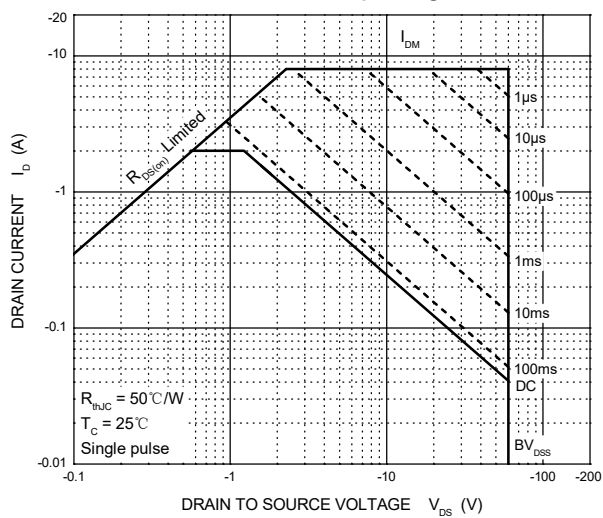


Typical Characteristics

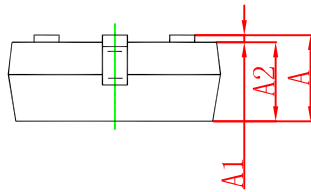
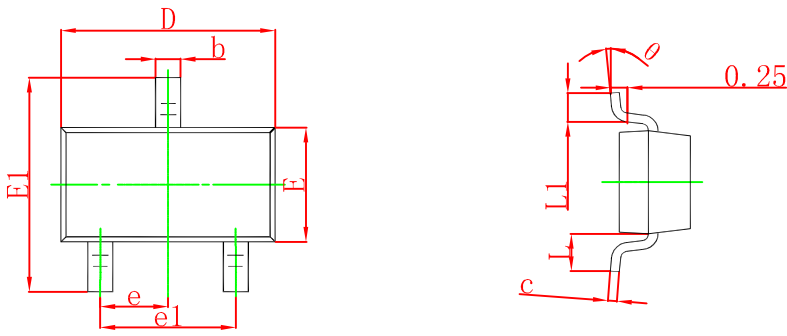
Transient Thermal Impedance, Junction-Case



Maximum Safe Operating Area

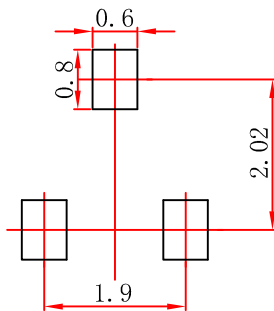


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

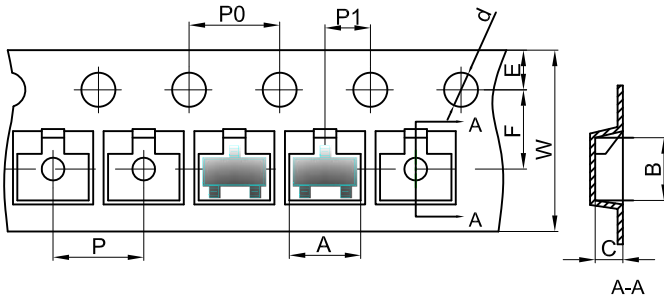
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape



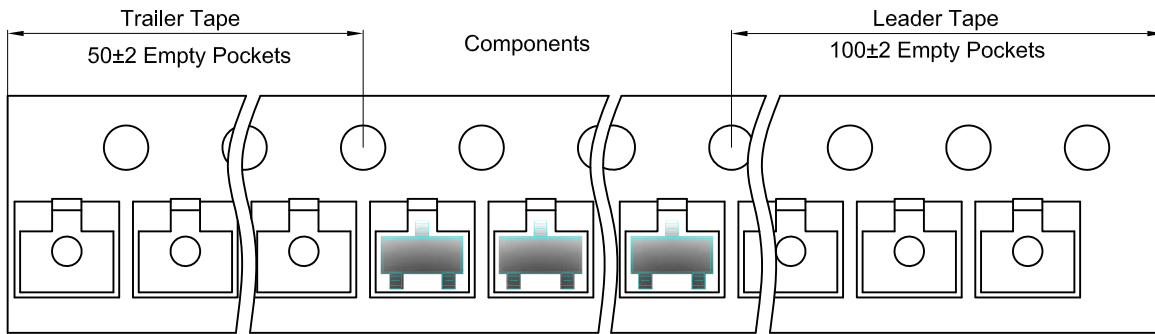
Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

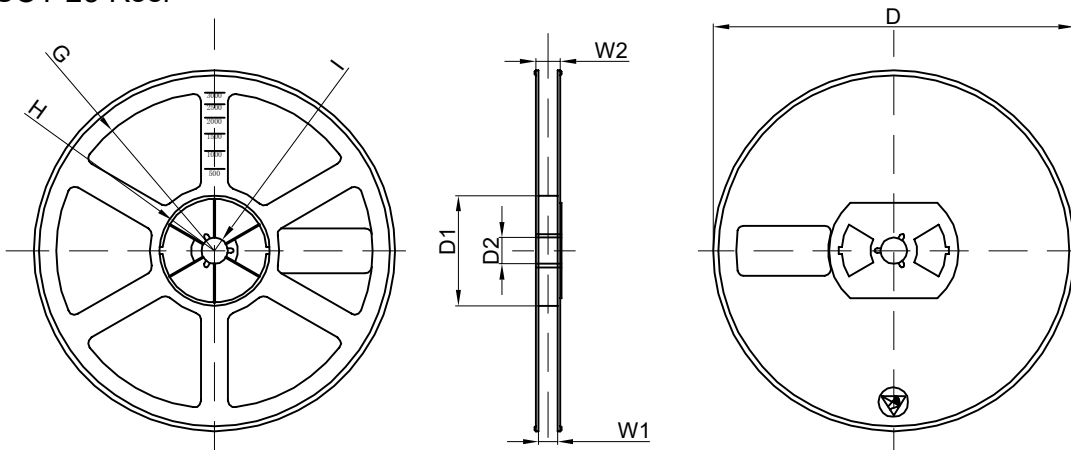
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	